RAM ENTERPRISE

THE POWER SOLUTIONS



MEGA Econo DUAL

IGBT-MOSFET DRIVER (Electrical) PART CODE : 220221050

Excellent Plug & Play solution!!

Features

- 2X4 Watt Compact Dual channel driver
- **>** Switching frequency up to 20 KHz
- ±35A gate current, +15V/-10V
- **>** Drive up to 1700V IGBT Module
- 14-PIN Electrical Interface
- **>** Extremely reliable & rugged design
- Integrated short-circuit soft shutdown

- Direct & half bridge modes
- ➤ Less than 1 uS delay time
- Less aging effect due to ASIC
- Primary/Sec. under voltage lockout
- Vce monitoring for short circuit current
- **Superior EMI-EMC**
- IGBT mount Plug & Play solution
- Advance active clamping for over voltage protection.

Benefits

- ➤ On board isolated DC-DC converter No need of separate SMPS.
- ➤ Interface for 12.0V...15 V logic level Direct compatible with any Controller.
- **TRANC** Feedback signal to interface with controller.
- ➤ Single fault feedback signal to interface with controller.
- **Field configurable blocking time Flexibility in your hand, use any make IGBT !!**
- ▶ Safe isolation to IEC 61800-5-1, IEC-60664-1 & En50178, protection class II
- 🚩 User selectable Rg(on) & Rg(off)

Application



WIND TURBINE



RAILWAY CONVERTER



SOLAR INVERTER

AC-Side

CONVERTER - INVERTER



INDUCTION HEATING & MELTING

"Drive the IGBT with experience hand"

WEB: www.ramenterprise.co.in



Technical Specification

Recommended Operating condition

Power Supply & Monitoring	MIN TYP MAX
1. Supply Voltage Vcc to GND :	14.5 15 15.5 V
2. Supply Current Icc (Without Load):	90mA (@25KHz PWM I/P)
3. Under Voltage Primary, Set Fault :	11.3 12.0 12.7 V
Clear Fault :	11.9 12.6 13.3 V
Secondary, Set Fault :	11.5 12.0 12.5 V
Clear Fault :	12.1 12.6 13.1 V

Logical Inputs & Outputs

1. Input Bias Current	: 190 µA
2. Interface Logic level	: 12.0 V 15.0 V logic level
3. Turn-on threshold	: 12 V (typ)
4. Turn off threshold	: 10.7 V (typ)
5. SOx output , failure Condition	: 0.7 V Max., I (SOx) < 20mA total

Short-Circuit Protection

: Diode sense method : 4.95 V (Internally Fix)

- 1. Vce-monitoring threshold Isc Trip adjustment R3, R7 : 33K (Vce:3.45 V-2000A)
- 2. Response(blanking) time
- 3. Minimum response time
- : 4.5 µSec (C7,C16: 150pF) Factory Set : 1.2 µSec
- 4. Available blocking time (R4) 5. Minimum blocking time (R4)
- : 49 mSec (User Selectable 100K) : 9 µSec(0E)

Timing Characteristic (Input to Output of Driver board under No-Load) 1. Turn-on delay t_{d(on)} :916 nS, Max. 2. Turn-off delay t_{d(off)} :816 nS, Max.

For detail timing information of driver core, refer part specific datasheet.

Protection Available on driver board

1. Primary/Secondary Under voltage monitoring & error feedback.

- 2. Power supply reverse polarity.
- 3. Advance active clamping, For IGBT Over Voltage.
- 4. Vce monitoring for short circuit current.
- 5. Schmitt trigger at the Input stage, highly susceptible to noise.
- 6. Interfacing with user's control circuit via EXTRESET pin so fault latching possible.(Optional for future expansion)

Electrical Isolation

Test voltage (50 Hz/1 sec)

1. Primary to secondary side · 5 0 KV 2. Secondary to secondary side :4.0 KV

This gate driver is suited for HiPot testing. Nevertheless, it is strongly recommended to limit the testing time to 1s slots as stipulated by EN 50178. Excessive HiPot testing at voltages much higher than $1200V_{AC(eff)}$ may lead to insulation degradation. No degradation has been observed over 1 min. testing at 5000V_{AC(eff)} Each driver core production sample shipped to customers has undergone 100% testing at the given value or higher for 1s.

Output Voltage / Current / Power

1. Turn-on voltage, V _{GHx}	: 15.0 V, any load condition
2. Turn-off voltage, V _{GLx}	: -10.1 V, No load
3. Turn-off voltage, V _{GLx}	:-9.5 V@4W
4. Turn-off voltage, V _{GLx}	:-9.3 V@6W
5. Gate Peak Current I _{out}	: ±35 Amp
5. Internal Gate resistance	: 0.5 Ω
6. External Gate resistance	: Minimum 1 Ω
7. Switching frequency F	: 10 Khz
8. Output Power	: 4.0 W, T _{amb} <85 °C
	: 6.0 W , T _{amb} < 70 °C

Part used on Plug & play driver : 2SC0435T2H0-17 from Power Integration (for more detail, kindly check part specific datasheet from PI)

THE POWER SOLUTIONS

Environmental

Working temperature Storage temperature

: -40 to 85°C

: INFINEON / SEMIKRON /FUJI

Driving Capability The EconoPACK drives all Econo-dual IGBT modules up to 900A, 1700 V. e.g. FF900R12ME7/CM800DX-24T1/2MBI800XNE120-50 power depends on switching frequency so in case of any doubt during selection process please contact.

Interfacing with Control Circuit

Electrical

- ERROR : High (Normal) to Low (Error) (Jp1 SHORT (1-2)) Low (Normal) to High (Error) (Jp1 SHORT - (2-3)) Open Collector output (Optional).
- EXTRST : 5 µSec high to low Pulse, Do ground if not used in circuit. (Optional for future use).

NTC : Output in Resistance.

LED Indication

Power ON: Green (Normally ON, Off during Power supply fault) ERROR (ER_TOP, ER_BOT): RED (Normally off, On during FAULT) (ERROR on individual output channel)

ORDERING CODE - 220221050

MEGA Econo DUAL	Description
	4W, 35A, 20KHz 1700V CLASS IGBT DRIVER ELECTRICAL Interface
220221050	Default Gate Resistor: 0.5E Rg(On), 0.6E Rg(Off)

Interfacing with Control Circuit INDUT Dotail 14 Din EPC

INTO Detail 14 I III I ICC.					
1,5,7	NC	3	ERROR		
2- (Bottom)	INB	6	EXTERNAL RESET		
4- (Top)	INA		(IF NOT IN USE - GND)		
8,9	+15V	13,14	NTC OUTPUT		
10,11,12	GND				

Mechanical Dimension

PCB : 110 mm X 72 mm Mounting Hole : Direct mount on IGBT terminals Enclosure : Open Frame Weight: 0.5 Kg





: -40 to 90 °C

ıΑ V..... 15.0 V logic level